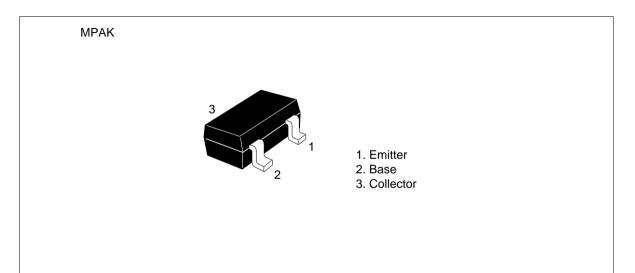
Silicon NPN Epitaxial

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Application

UHF / VHF wide band amplifier

Outline





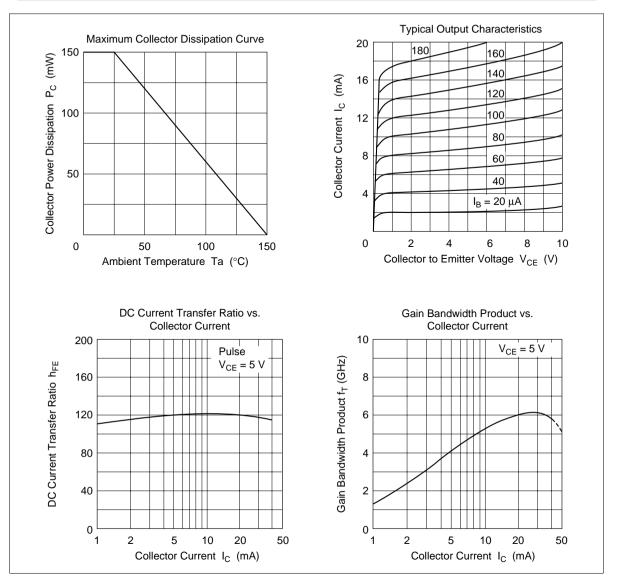
Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

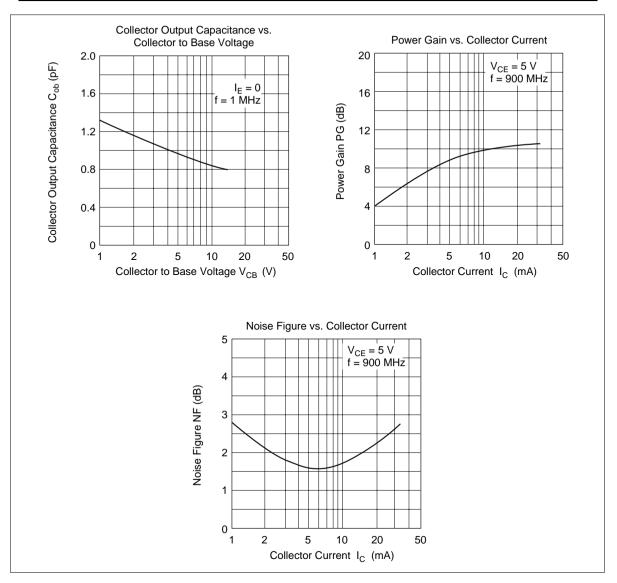
Item	Symbol	Ratings	Unit	
Collector to base voltage	V _{CBO}	15	V	
Collector to emitter voltage	V _{CEO}	11	V	
Emitter to base voltage	V _{EBO}	2	V	
Collector current	Ι _c	50	mA	
Collector power dissipation	Pc	150	mW	
Junction temperature	Тј	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

Electrical Characteristics ($Ta = 25^{\circ}C$)

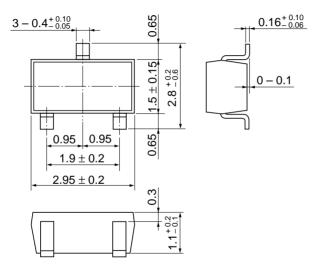
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	15	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector cutoff current	I _{CEO}	—	—	1	μΑ	V_{ce} = 10 V, R_{be} = ∞
Emitter cutoff current	I _{EBO}	—	—	1	μΑ	$V_{EB} = 1 V, I_{C} = 0$
Collector cutoff current	I _{CBO}	—	—	1	μΑ	$V_{CB} = 12 \text{ V}, \text{ I}_{E} = 0$
DC current transfer ratio	h_{FE}	50	120	250		V_{ce} = 5 V, I_c = 20 mA
Collector output capacitance	Cob	—	1.0	1.5	рF	$V_{CB} = 5 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Gain bandwidth product	f _T	—	6.0	—	GHz	$V_{ce} = 5 \text{ V}, \text{ I}_{c} = 20 \text{ mA}$
Power gain	PG	_	10	_	dB	V_{ce} = 5 V, I _c = 20 mA, f = 900 MHz
Noise figure	NF	—	1.6	—	dB	V_{ce} = 5 V, I _c = 5 mA, f = 900 MHz

Note: Marking is "IS-".





Unit: mm



Hitachi Code	MPAK
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.011 g

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